Diode Semiconductor Device - Page 1 of 1



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Inclosure Materi	
Glass	
Overall Length:	
	nches and 0.350 inches
Terminal Length	1:
1.000 inches	
Overall Diamete	
	nches and 0.265 inches
	ally-electrically Connected To Case:
Cathode	
Mounting Metho	bd:
Terminal	
Features Provid	ed:
Hermetically seal	led case
Semiconductor	Material:
Silicon	
Voltage Rating I	n Volts Per Characteristic:
23.1 regulator v	oltage
Current Rating I	Per Characteristic:
43.00 milliampere	es source cutoff current horsepower metric
Power Rating Pe	er Characteristic:
1.0 watts small-s	ignal input power, common-collector preset
Maximum Opera	ating Tempurature Per Measurement Point:
175.0 degrees ce	elsius ambient air
Test Data Docur	ment:
81349-mil-s-1950	00 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental an	nd performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type A	And Quantity:
2 uninsulated wir	e lead
Specification Da	ata:
81349-mil-s-1950	00/115 government specification
Shelf Life:	
N/a	
Unit Of Measure	n.
Demilitarization	
No	
Fiig:	
A110a0	